JCT151A-650RH 12A SCR Rev.A.1.1

DESCRIPTION:

With high ability to withstand the shock loading of large current, JCT151A-650RH of silicon controlled rectifiers provides high dV/dt rate with strong resistance to electromagnetic interference. It is especially recommended for use on solid state relay, motorcycle, power charger, T-tools etc. From all three terminals to external heatsink, JCT151A-650RH provides a rated insulation voltage of 2500 $V_{RMS,}$ complying with UL standards (File ref: E252906).
Package TO-220A is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
V_{DRM}/V_{RRM}	650	V
I_{GT}	”15	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-150	
Repetitive peak off-state voltage (T_j=25)	V_{DRM}	650	V
Repetitive peak reverse voltage (T_j=25)	V_{RRM}	650	V

Average on-state current (T_C 0-

Peak gate current (t_p=20 s , T_j=150)	I_{GM}	4	A
Average gate power dissipation (T_j=150)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W oTc 0 Tw0T<</

FIG.1: Maximum power dissipation versus RMS on-state current

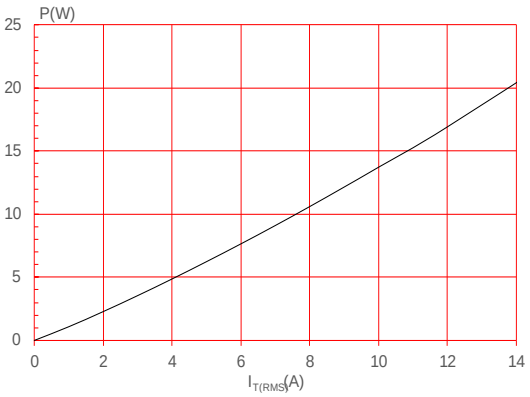


FIG.2: RMS on-state current versus case temperature

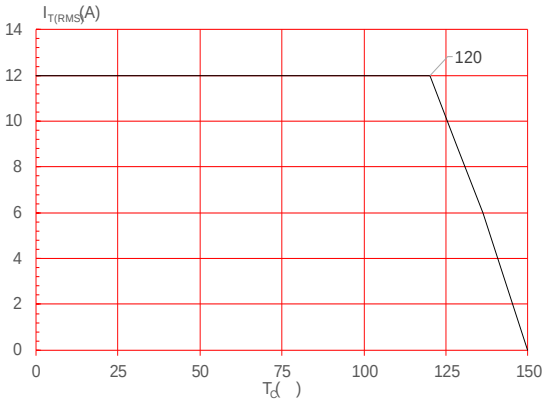
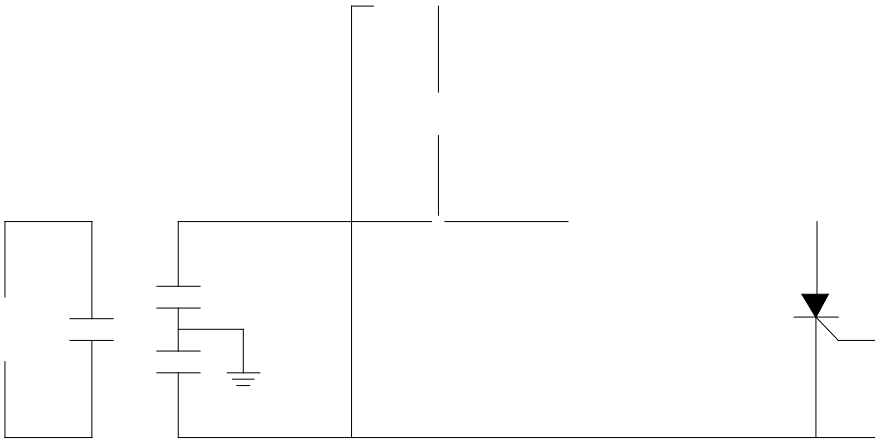


FIG.3: Surge peak on-state current versus number of cycles

FIG.4: On-state characteristics

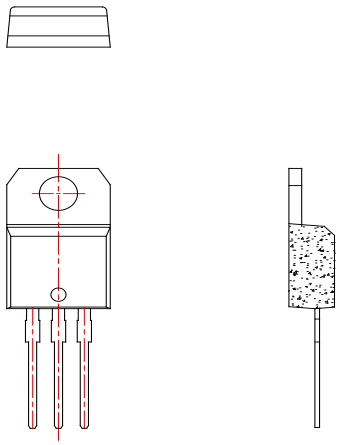
FIG.7 ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards.



ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	

PACKAGE MECHANICAL DATA



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